

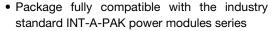
## Vishay Semiconductors

## Three Phase Bridge (Power Modules), 40 A



| PRIMARY CHARACTERISTICS |                    |  |  |
|-------------------------|--------------------|--|--|
| I <sub>O</sub>          | 40 A               |  |  |
| $V_{RRM}$               | 1600 V             |  |  |
| Package                 | MTK                |  |  |
| Circuit configuration   | Three phase bridge |  |  |

#### **FEATURES**





- High thermal conductivity package, electrically insulated case
- Excellent power volume ratio, outline for easy connections to power transistor and IGBT modules
- 4000 V<sub>RMS</sub> isolating voltage
- · Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **DESCRIPTION**

A range of extremely compact, encapsulated three phase bridge rectifiers offering efficient and reliable operation. They are intended for use in general purpose and heavy duty applications.

| MAJOR RATINGS AND CHARACTERISTICS |                 |             |                   |  |  |
|-----------------------------------|-----------------|-------------|-------------------|--|--|
| SYMBOL                            | CHARACTERISTICS | VALUES      | UNITS             |  |  |
|                                   |                 | 40 (50)     | А                 |  |  |
| I <sub>O</sub>                    | T <sub>C</sub>  | 85 (60)     | °C                |  |  |
| I <sub>FSM</sub>                  | 50 Hz           | 270         | ^                 |  |  |
|                                   | 60 Hz           | 280         | А                 |  |  |
| l <sup>2</sup> t                  | 50 Hz           | 365         | kA <sup>2</sup> s |  |  |
|                                   | 60 Hz           | 325         | KA-S              |  |  |
| l²√t                              |                 | 3650        | kA²√s             |  |  |
| V <sub>RRM</sub>                  |                 | 1600        | V                 |  |  |
| T <sub>Stg</sub>                  | Pongo           | -40 to +150 | °C                |  |  |
| T <sub>J</sub>                    | Range           | -40 to +150 |                   |  |  |

### **ELECTRICAL SPECIFICATIONS**

| VOLTAGE RATINGS |                 |  |  |   |  |
|-----------------|-----------------|--|--|---|--|
| TYPE NUMBER     | VOLTAGE<br>CODE | V <sub>RRM</sub> , MAXIMUM REPETITIVE<br>PEAK REVERSE VOLTAGE<br>V | V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE<br>PEAK REVERSE VOLTAGE<br>V | I <sub>RRM</sub> MAXIMUM<br>AT T <sub>J</sub> MAXIMUM<br>mA |  |
| 40MTK           | 160             | 1600   | 1700   | 10  |  |





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| FORWARD CONDUCTION                           |                     |  |                                     |                     |            |                   |
|--|---------------------|--|-------------------------------------|---------------------|------------|-------------------|
| PARAMETER                                    | SYMBOL              | TEST CONDITIONS  |                                     | VALUES              | UNITS      |                   |
| Maximum DC output                            | I-                  | I <sub>O</sub> 120° rect. conduction angle                                 |                                     | 40 (50)             | Α          |                   |
| current at case temperature                  | 10                  |  |                                     | 85 (60)             | °C         |                   |
|  | I <sub>FSM</sub>    | t = 10 ms  | No voltage                          | Initial             | 270        | Α                 |
| Maximum peak, one-cycle                      |                     | t = 8.3 ms   | reapplied                           |                     | 280        |                   |
| forward, non-repetitive<br>surge current     |                     | t = 10 ms  | 100 % V <sub>RRM</sub><br>reapplied |                     | 225        |                   |
| oa.ge can em                                 |                     | t = 8.3 ms   |                                     |                     | 240        |                   |
| Maximum I <sup>2</sup> t for fusing          |                     | t = 10 ms  | No voltage                          | $T_J = T_J$ maximum | 365        | kA <sup>2</sup> s |
|  | l <sup>2</sup> t    | t = 8.3 ms   | reapplied                           |                     | 325        |                   |
|  |                     | t = 10 ms  | 100 % V <sub>RRM</sub>              |                     | 253        |                   |
|  |                     | t = 8.3 ms   | reapplied                           |                     | 240        |                   |
| Maximum I <sup>2</sup> √t for fusing         | I <sup>2</sup> √t   | t = 0.1 ms to 10 ms, no voltage reapplied                                  |                                     | 3650                | A²√s       |                   |
| Low level value of threshold voltage         | V <sub>F(TO)1</sub> | (16.7 % x $\pi$ x $I_{F(AV)}$ < $I$ < $\pi$ x $I_{F(AV)}$ ), $T_J$ maximum |                                     | 0.78                | V          |                   |
| High level value of threshold voltage        | V <sub>F(TO)2</sub> | $(I > \pi \times I_{F(AV)})$ , $T_J$ maximum                               |                                     | 0.9                 | V          |                   |
| Low level value of forward slope resistance  | r <sub>f1</sub>     | (16.7 % x $\pi$ x $I_{F(AV)}$ < $I$ < $\pi$ x $I_{F(AV)}$ ), $T_J$ maximum |                                     | 15                  | <b>~</b> 0 |                   |
| High level value of forward slope resistance | r <sub>f2</sub>     | $(I > \pi \times I_{F(AV)})$ , $T_J$ maximum                               |                                     | 14.1                | mΩ         |                   |
| Maximum forward voltage drop                 | $V_{FM}$            | $I_{pk}$ = 100 A, $T_J$ = 25 °C, $t_p$ = 400 $\mu$ s single junction       |                                     | 2.02                |            |                   |
| RMS isolation voltage                        | V <sub>ISOL</sub>   | T <sub>J</sub> = 25 °C, all terminal shorted<br>f = 50 Hz, t = 1 s         |                                     | 4000                | V          |                   |

| THERMAL AND MECHANICAL SPECIFICATIONS                   |             |                                   |   |             |       |
|---|-------------|-----------------------------------|---|-------------|-------|
| PARAMETER   |             | SYMBOL TEST CONDITIONS            |   | VALUES      | UNITS |
| Maximum junction operating a storage temperature range  | nd          | T <sub>J</sub> , T <sub>Stg</sub> |   | -40 to +150 | °C    |
|   |             |                                   | DC operation per module   | 0.41        |       |
| Maximum thermal resistance, junction to case            |             | R <sub>thJC</sub>                 | DC operation per junction   | 2.46        | K/W   |
|   |             |                                   | 120° rect. conduction angle per module  | 0.45        |       |
|   |             | -                                 | 120° rect. conduction angle per junction  | 2.7         |       |
| Maximum thermal resistance, case to heatsink per module |             | R <sub>thCS</sub>                 | Mounting surface smooth, flat and greased   | 0.03        |       |
| Maratina Israel 40.07                                   | to heatsink |                                   | A mounting compound is recommended and the  | 4 to 6      | Nm    |
| Mounting torque ± 10 %                                  | to terminal |                                   | torque should be rechecked after a period of 3 hours to allow for the spread of the compound. | 3 to 4      |       |
| Approximate weight                                      |             |                                   | Lubricated threads.   | 176         | g     |



### www.vishay.com

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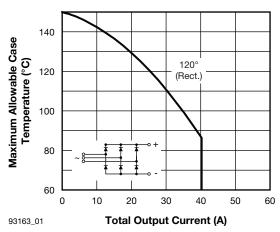
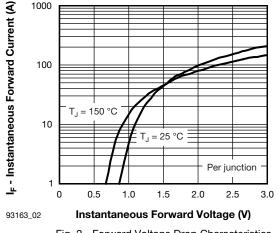
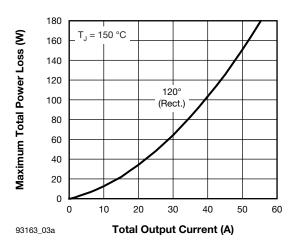


Fig. 1 - Current Ratings Characteristics



1000

Fig. 2 - Forward Voltage Drop Characteristics



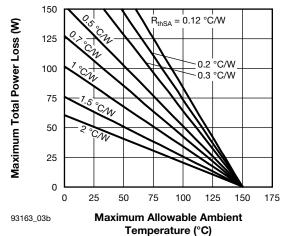


Fig. 3 - Total Power Loss Characteristics

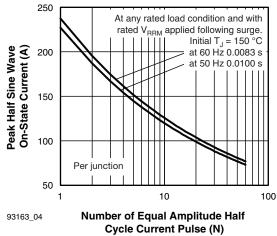


Fig. 4 - Maximum Non-Repetitive Surge Current

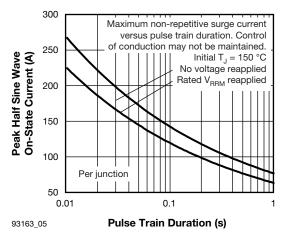


Fig. 5 - Maximum Non-Repetitive Surge Current

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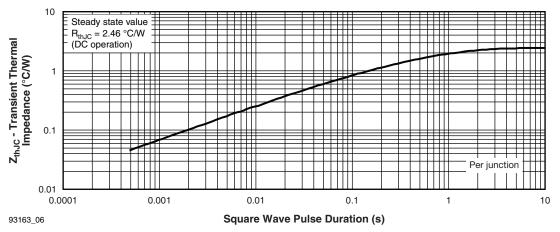
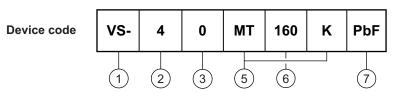


Fig. 6 - Thermal Impedance Z<sub>thJC</sub> Characteristics

### **ORDERING INFORMATION TABLE**

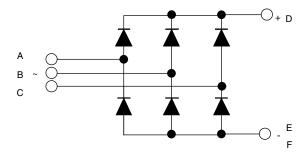


- Vishay Semiconductors product
- 2 Current rating code: 4 = 40 A (average)
- Three phase diodes bridge
- 4 Essential part number
- 5 Voltage code x 10 = V<sub>RRM</sub> (see Voltage Ratings table)
- 6 PbF = lead (Pb)-free

### Note

• To order the optional hardware go to <a href="www.vishay.com/doc?95172">www.vishay.com/doc?95172</a>

### **CIRCUIT CONFIGURATION**



| LINKS TO RELATED DOCUMENTS |                          |  |
|----------------------------|--------------------------|--|
| Dimensions                 | www.vishay.com/doc?95004 |  |



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